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Tuning the Lattice Parameter of In$_x$Zn$_y$P for Highly Luminescent Lattice-matched core/shell Quantum Dots

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ABSTRACT

Colloidal quantum dots (QDs) show great promises as LED phosphors due to their tuneable narrow-band emission and ability to produce high-quality white light. Currently, the most suitable QDs for lighting applications are based on cadmium, which presents a toxicity problem for consumer applications. The most promising cadmium-free candidate QDs are based on InP, but their quality lags much behind that of cadmium based QDs. This is not only because the synthesis of InP QDs is more challenging than that of Cd-based QDs, but also because the large lattice parameter of InP makes it difficult to grow an epitaxial, defect free shell on top of such material. Here we propose an original approach to overcome this problem by alloying InP nanocrystals with Zn$^{2+}$ ions, which enables the synthesis of In$_x$Zn$_y$P alloy QDs having lattice constant that can be tuned from 5.93 Å (pure InP QDs) down to 5.39 Å by simply varying the concentration of the Zn precursor. This lattice engineering allows for subsequent strain-free, epitaxial growth of a ZnSe$_x$S$_{1-x}$ shell with lattice parameters matching that of the core. We demonstrate, for a wide range of core and shell compositions (i.e. varying x, y and z), that the photoluminescence quantum yield is maximal (up to 60%) when lattice mismatch is minimal.
INTRODUCTION

Colloidal quantum dots (QDs) have attracted considerable interest for use in optoelectronic and biomedical devices, due to their unique optical and electrical properties.\textsuperscript{1-3} In particular, QDs are seen as ideal candidates to replace current (red) phosphors in LEDs as they could significantly enhance the LED efficiency and colour purity due to their tuneable narrow-band emission.\textsuperscript{3,4} For QDs to be employed in lighting applications they must have the stringent requirements of high photoluminescence (PL) quantum yield (QY) and high stability. Whilst these requirements have been met, to a high degree, for Cd based QDs,\textsuperscript{5,6} the toxicity of cadmium is a major issue for consumer applications. InP-based QDs are among the most investigated non-toxic Cd-free systems, owing to their comparable emission range.\textsuperscript{7-25} However, in terms of PL QY and PL stability they cannot yet compete with Cd-based QDs.

The predominant strategy for achieving higher PL efficiency is to grow a shell of a wider band gap material around the QD core, resulting in core/shell particles.\textsuperscript{1} The shell material must be carefully chosen, not only in terms of band gap and relative positions of valence and conduction band edges with respect to those of the core, but also in terms of crystal structure and lattice parameter, in order to prevent the build-up of an excessive strain at the core-shell interface that would result in poor PL QY of the final QDs.\textsuperscript{1,2,26,27} Therefore finding strategies to avoid defect formation during the shell growth represents one of the main challenges in the field of nanomaterials for lighting applications. In this regard, InP presents an additional limitation: it has a large lattice constant ($a=5.93$ Å), which makes it incompatible with standard shell materials (i.e. GaP, $a=5.45$ Å;\textsuperscript{28} ZnS, $a=5.42$ Å;\textsuperscript{29} ZnSe, $a=5.66$ Å\textsuperscript{29}). In the past decades, strategies to overcome this problem have focused on adapting these shells to better match the InP core by the use of a graded core-shell interface, or the growth of an intermediate buffer layer to ensure low
lattice strain.\textsuperscript{12–15} However, these strategies necessitate additional steps in the fabrication of core/shell QDs, thereby increasing the complexity of the synthetic procedure. Additionally, these methods have not succeeded in producing InP QDs with PL QY and stability comparable to CdSe based QDs. Clearly other approaches are required.

Here we present an original approach where an InP core is designed with a specific crystal lattice constant such that it matches the lattice of the shell material. We have developed a simple one-pot method for the synthesis of zinc-blende In\textsubscript{x}Zn\textsubscript{y}P alloy QDs where Zn\textsuperscript{2+} ions are incorporated in the InP structure as substitutional dopants on In\textsuperscript{3+} sites. Depending on the concentration of the Zn precursor added, the lattice constant of the resulting alloy nanocrystals can be tuned from 5.93 Å of the pure InP QDs down to 5.39 Å.

First, we report a comprehensive study of In\textsubscript{x}Zn\textsubscript{y}P alloy QDs encompassing extensive optical, structural and chemical characterization. Although the addition of Zn to the synthesis of InP nanocrystals has become common practice in the last years,\textsuperscript{11–17,21–25} very little has been reported on the actual role of the Zn. The few reports on this topic have focused on the effect on the optical properties, but structural aspects were not investigated.\textsuperscript{21,24,30} Here instead we carry out a detailed investigation on the location of Zn\textsuperscript{2+} in the InP QD lattice. Such compositional tunability is then exploited to match the lattice parameter of the In\textsubscript{x}Zn\textsubscript{y}P cores to that of a range of shell materials (GaP, ZnSe and ZnS) which otherwise would not be compatible with InP. To validate our approach, we synthesized In\textsubscript{x}Zn\textsubscript{y}P/ZnSe\textsubscript{z}S\textsubscript{1–z} core/shell QDs by varying the lattice constants of both core and shell. In all cases the highest PL QY (up to 60\%) was measured when the lattice mismatch was minimum. This demonstrates that the interfacial lattice mismatch is the dominant factor determining the PL QY in these core-shell QDs and that alloying the core to match the shell can effectively alleviate it. Our approach offers significant advantages compared to
previous methods, as it allows for a wider range of shell materials to be used. Additionally, it is a straightforward way to increase the quality of InP based QDs, making them suitable candidates for non-toxic LED applications.

**EXPERIMENTAL SECTION**

**Materials:** Indium(III) acetate (In(OAc)_3, 99.99%), palmitic acid (PA, C_{15}H_{31}COOH, 99.99%, stored at -20 °C), tris(trimethylsilyl)-phosphine (P(SiMe_3)_3, 95%), zinc(II) acetate (Zn(OAc)_2, 99.99 %), ammonium sulfide solution (S(NH_4)_2, 20% in H_2O), 1-octadecene (ODE, 95%) formamide (FA, 99%), dimethylformamide (DMF, 99%) Zn stearate (technical grade), Sulfur powder (99.98% trace metals basis), trioctylphosphine (TOP, 90% technical grade) were purchased from Sigma-Aldrich. Selenium powder (99.98% trace metals basis) was purchased by Chem Pure. All the chemicals were used without further purification.

**Synthesis of In_xZn_yP core QDs:** In a typical synthesis using a Zn/In molar ratio of 1, in a three-neck flask 35 mg In(OAc)_3 (0.12 mmol), 11 mg Zn(OAc)_2 (0.06 mmol) and 91 mg palmitic acid (0.36 mmol) were mixed in 7 mL ODE. The solution was degassed under vacuum for an hour at 140°C. After heating up the solution to 300 °C under nitrogen flow, 17 µL (P(TMS)_3) (0.06 mmol; 15 mg) in 1 mL ODE was rapidly injected. The temperature was then lowered to 270 °C and held for 2h. The In_xZn_yP NCs were washed three times by dispersion in toluene followed by precipitation by addition of a mixture ethanol:acetone (1:3), and stored in toluene or hexane in a N_2 filled vial in the glovebox. The amount of zinc precursors was varied between 0 mg (for Zn/In=0) and 220 mg (for Zn/In=10), while the In(OAc)_3 and P(TMS)_3 were kept constant.
Synthesis of Zn$_x$P$_y$ core QDs: Zn$_x$P$_y$ nanoparticles was synthesized following the method describe above for In$_x$Zn$_y$P QDs, without addition of In(OAc)$_3$ in the reaction mixture. Zn/P ratios of 1 and 2 were used.

Synthesis of In$_x$Zn$_y$P/ ZnSe$_z$S$_{1-z}$ core/shell QDs: For a typical synthesis, 0.325g of Zn stearate in 1.5 mL of ODE, were added into a three next flask containing 2ml of as synthesized In$_x$Zn$_y$P cores at room temperature. Separately, a 1M stock solution of TOP-Se was prepared by dissolving 4 mmol of Se powder in 4 mL of TOP. A 1M TOP-S stock solution was prepared with the same procedure as TOP-Se. Upon addition of the Zn precursor, the temperature of the reaction mixture was set to 300°C with a heating rate of 10°C / min. When the temperature was about 90°C, a total of 0.5 mL of the anion stock solution (Se-TOP + S-TOP) was added. The ZnSe$_z$S$_{1-z}$ composition was changed by varying the Se-TOP and S-TOP precursor amount: for example in case of $z=0$, 0.5 mL of 1M TOP-S was added, while in case of $z=0.5$, 0.25 mL of 1M TOP-Se and 0.25 mL of 1M TOP-S were added. We verified by ICP-OES measurements that the Se/S ratio in the shell matches the Se/S precursor ratio (See SI Table S2). The reaction was kept at 300°C for 20 min, and subsequently quenched by lowering the temperature. The product was purified by dispersion in chloroform (2mL) followed by precipitation by addition of a mixture of ethanol:acetone (1:4). The obtained particles were stored in toluene in a N$_2$ filled vial in the glovebox.

Ligand exchange: A colloidal dispersion of washed NCs with organic ligands was prepared in nonpolar solvents like toluene, while the solution of inorganic ligands was prepared in polar formamide (FA) immiscible with toluene. The exchange of inorganic ligand with S$^{2-}$ was carried out in a N$_2$ glove box. 20µl of (NH$_4$)$_2$S solution was added to 1 mL of FA and mixed with 1ml of a NC dispersion in toluene. The mixture was sonicate for 15 minutes in a sonic bath at 60°C,
leading to a complete phase transfer of the NCs from toluene to the FA phase. The phase transfer can be easily monitored by the colour change of toluene (red to colourless) and FA (colourless to red) phases. The FA phase was separated and acetone was added as non-solvent to precipitate the particles. To remove any remaining nonpolar organic ligand a further washing step with toluene as a non-solvent was applied. This was repeated twice. The QDs were then dispersed in dimethylformamide (DMF) for further analysis and stored in a N₂ filled vial in the glovebox.

**Characterization**

**Absorption and emission UV-VIS measurements:** QD samples for optical analysis were prepared by diluting the stock solutions in toluene in a 1 cm quartz cuvette. Absorption spectra were measured on the Perkin Elmer L900 and L40 UV/VIS spectrometers. Emission spectra were obtained using a PTI QuantaMaster with a 75W xenon lamp, using an excitation wavelength at 400 nm.

**Absolute QY measurements:** QD samples for PL QY measurements were prepared by diluting the purified stock solutions in toluene. PL quantum yields (QY) were determined using an integrated sphere setup at Philips Research Laboratory. The set up consisted of a 445 nm diode laser, a Labsphere 6” integrating sphere and a fiber coupled spectrometer (USB 4000, Ocean Optics). The combination of sphere, fiber and spectrometer was calibrated with a light source of known emission characteristics.

**Time-resolved PL measurements.** QD samples were prepared by diluting the stock solutions in toluene in a 1 cm quartz cuvette. PL lifetimes were recorded using an Edinburgh LifeSpec spectrometer equipped with a single photon counter. The samples were excited at 405 nm with a picosecond pulsed diode laser (Hamamatsu, M8903-01, I₀ = 4 x 10¹² photons/cm²).
Transmission electron microscopy (TEM) and Energy dispersive X-ray (EDX) spectroscopy. Samples for analysis were obtained by dipping carbon coated copper TEM grids in the NPs solution and blotting on a filter paper at room temperature. TEM images and elemental analysis were obtained with a Philips CM30, INCA x-sight operating at 120eV.

Inductively Coupled Plasma (ICP) Optical Emission Spectroscopy (OES) elemental analysis. ICP measurements were carried out using a iCAP 6500 Thermo spectrometer. All chemical analyses performed by ICP-OES were affected by a systematic error of about 5%. Samples were dissolved in HCl/HNO3 3:1 (v/v).

X-ray Photoelectron Spectroscopy (XPS). Samples for XPS were prepared by drop-casting a solution of NCs onto silicon wafers. XPS measurements were performed on a Kratos Axis Ultra DLD spectrometer, using a monochromatic Al Kα source operating at 15 kV and 20 mA. Wide scans were acquired at analyser pass energy of 160 eV, while high resolution narrow scans were performed at constant pass energy of 10 eV and steps of 0.1 eV. The photoelectrons were detected at a take-off angle $\Phi = 0^\circ$ with respect to the surface normal. The pressure in the analysis chamber was maintained below $5 \times 10^{-9}$ Torr for data acquisition. The data were converted to VAMAS format and processed using CasaXPS software, version 2.3.16. The binding energy (BE) scale was internally referenced to the C 1s peak (BE for C–C = 284.8 eV).

Powder X-ray diffraction patterns (XRD). Specimens for the XRD measurements were prepared in a glove box by dropping a concentrated NCs solution onto a quartz zero-diffraction single crystal substrate. XRD measurements were performed on a PANanalytical Empyrean X-ray diffractometer equipped with a 1.8 kW CuKα ceramic X-ray tube, PIXcel3D 2x2 area detector and operating at 45 kV and 40 mA. The diffraction patterns were collected in air at room
temperature using Parallel-Beam (PB) geometry and symmetric reflection mode. XRD data analysis was carried out using HighScore 4.1 software from PANalytical.

**Calculation of lattice parameters.** In order to calculate the lattice constant of the measured QDs Nelson-Riley plots were made (using the three reflections in the 2θ scans) to determine the In$_x$Zn$_y$P lattice parameters, as shown in Figure 1d. The uncertainty is on the order of 10$^{-2}$ Å, which is defined by z-position accuracy, 2theta step size, and the slope of Nelson-Riley plots.\textsuperscript{32–34} The position of the three reflections was obtained by fitting the diffraction peaks with a Gaussian function using Origin Pro 9.0. Note that the Nelson-Riley method minimises systematic error contributions to the uncertainty on the quoted lattice parameters, as reported in reference.\textsuperscript{32–34}

**Electrophoresis measurements:** The charge of the synthesized In$_x$Zn$_y$P QDs was determined through measurement of the electrophoretic mobility. 750 µL of a diluted QDs solution in toluene was loaded into the Malvern PCS1115 non-aqueous dip cell and measured on Malvern Zetasizer Z Nano operating at 25°C. The electrophoretic mobility $\mu_e$ was converted to the ζ-potential using the Hückel approximation, averaged over three measurements, according to:

$$\zeta = \frac{1.5\eta\mu_e}{\varepsilon\varepsilon_0}$$

Here the viscosity $\eta$ and the dielectric constant $\varepsilon$ depend on the type of solvent (toluene).

**Theoretical Calculations**

Initial geometries of quasi-spherical stoichiometric InP NCs were generated using a home-built software and assuming the bulk crystal structure. The dangling bonds of the resulting quantum dots were passivated with hydrogen atoms. Hydrogen atoms were here preferred organic surfactant molecules to ease the calculations. The scripts used to generate these initial geometries are available upon demand. Zinc atoms were then incorporated in the composition of these InP
NCs following three different methods. In the first method three Zn atoms (oxidation state +2) replaced 3 In (oxidation state +3) atoms in the lattice. To compensate the charges, 1 phosphorus atom (oxidation state -3) was removed at the surface of the NCs. In the second approach, only 2 Zn atoms replaced 2 In atoms and one additional Zn atom was introduced as an interstitial dopant to balance the charge. These two approaches were then iterated to obtain Zn/In ratio close to unity. The geometries of the resulting NCs were then fully relaxed at the density functional level of theory (DFT). The Amsterdam Density Functional (ADF) package was used to perform these geometry optimizations.\textsuperscript{35-37} Due to some difficulties encountered during the electronic structure calculation in some systems, a large threshold of 1e-4 was used to stop the SCF cycles and a charge smearing up to 0.01 Hartree was employed. A scalable SCF approach was employed to accelerate the calculations. The simulations of the XRD spectra were done using the debyer software.\textsuperscript{37} A x-ray wavelength of 0.154 nm was used in agreement with the copper source used experimentally.

**RESULTS and DISCUSSIONS**

InP based QDs were prepared following an adaptation of the method described by Kim et al.\textsuperscript{12}: Zn palmitate was added to form In\textsubscript{x}Zn\textsubscript{y}P alloys. The Zn/In precursor ratio was varied between 0 and 20 (see SI for further details). The resulting particles had a diameter of about 3 nm (Figure 1a); by changing the concentration of Zn the size of the resulting QDs remained constant within the experimental error (see figure S1). To evaluate the amount of Zn incorporated in the QDs, we performed ICP-OES and XPS analyses on carefully washed In\textsubscript{x}Zn\textsubscript{y}P QDs synthesized using different Zn/In ratios (see Experimental Section for details on the washing procedure). Figure 1b clearly shows that when a relatively low amount of Zn precursor (Zn/In feed ratio below 2) is used, a quantitative amount of Zn is detected in the resulting QDs (green dashed line, Figure 1b).
A further increase in the Zn/In feed ratio results in an incomplete conversion of the Zn precursor, leading to saturation of the Zn/In ratio around 4 (red dashed line Figure 1b), even when a Zn/In ratio of 20 is used. For this reason for the remainder of this work we will only discuss samples synthesised with Zn/In feed ratios in the range 0 – 5.

To determine the location of the Zn atoms in the nanocrystals, the samples were investigated by XRD analysis combined with theoretical modelling (DFT calculations, see Experimental Section for details). The results of the structural characterization are described in Figure 1c-e. The expected crystal structure of InP is shown in Figure 1c (upper panel). The XRD pattern confirms that when no Zn precursor is added to the reaction flask, the phase of the resulting QDs is consistent with that of bulk zinc blende InP (Figure 1d, black pattern). The samples prepared with addition of Zn precursor exhibit the same XRD reflections, but with a systematic shift towards higher diffraction angles as the amount of Zn into the QDs is increased (Figure 1d and Figure S2), which indicates a contraction of the crystal lattice. No other side products, such as Zn\textsubscript{x}P\textsubscript{y} QDs (i.e. tetragonal or monoclinic Zn\textsubscript{2}P, or monoclinic or cubic Zn\textsubscript{3}P\textsubscript{2}), that would exhibit clear distinct XRD peaks, are observed (see Figure 1d top panel). Indeed, even cubic Zn\textsubscript{3}P\textsubscript{2} exhibits a different crystal structure, as depicted in the sketch of Figure 1c (lower panel).

To prove that, under our synthetic conditions, no Zn\textsubscript{x}P\textsubscript{y} phases were formed, the following control experiment was performed: a synthesis was done using only zinc and phosphorus precursors while keeping all the other reaction parameters fixed. This synthesis resulted in large nanoparticles with a broad size distribution (diameter of \(d = 8.3\pm3.2\) nm) (Figure S3 in SI). XRD analysis indicated that no phosphides were formed, but a Zn-Si complex with a hemimorphite crystal structure was identified. We can exclude that these particles are formed as side product during the synthesis of In\textsubscript{x}Zn\textsubscript{y}P QDs, as the XRD patterns do not show additional peaks of the
The hememorphite structure, and no large particles are visible in the TEM images of our QDs (Figure S1 and S3 in SI). The contraction of the InP lattice upon addition of Zn strongly suggests that Zn atoms are incorporated in the crystal structure, forming In$_x$Zn$_y$P alloy QDs. We can exclude that Zn$^{2+}$ ions are located only on the surface of the QDs, since in that case no shift of the XRD peaks would be observed.

To identify the position of the Zn ions inside the lattice of the QDs, we performed DFT geometry optimization of small quasi-spherical In$_x$Zn$_y$P QDs passivated with hydrogen atoms. The fully optimized structure of the QD was then used to compute the XRD reflections (see Experimental Section and SI for details on the calculations). Three different strategies were adopted to incorporate zinc: (i) only substitutional Zn$^{2+}$ was used; three In$^{3+}$ cations were hence substituted by three Zn$^{2+}$ cations and one P$^{3-}$ anion was removed from the surface of the QD, in order to preserve charge neutrality. (ii) two Zn$^{2+}$ were substituted onto In$^{3+}$ sites while a third Zn$^{2+}$ cation was placed at an interstitial position. (iii) three Zn$^{2+}$ were placed interstitially and two P$^{3-}$ anions were removed from the surface of the QD. We found a strong shift to smaller lattice constants (higher 2theta values) similar to the experimental observation, only when considering placing Zn ions substitutionally (strategy i). In the other scenarios we either observed a very small shift of the lattice constant (strategy ii) or a shift to a larger lattice constant (strategy iii). Hence the combination of XRD measurements and DFT calculations suggests that the contraction of the lattice originates from the progressive substitution of indium by zinc ions without introduction of interstitial zinc. The analysis of the bond length inside the QDs structures revealed that the average Zn-P bond length (0.245 nm) was 7.5% smaller than the average In-P bond length (0.265 nm). Furthermore, each substituted Zn atom induced a reduction of the In-P bond length in its direct vicinity (see SI for details Figure S4-S9).
XPS analyses further confirmed the formation of In$_x$Zn$_y$P alloys. XPS is normally considered to be a surface sensitive technique, with a typical penetration depth of up to 10 nm. However, in this case, as our QDs are around 3 nm in diameter, this technique probes the whole QD volume. The reference pure InP QD sample (black spectrum in figure 2a) shows a In 3d$_{5/2}$ peak centred at 444.1±0.2 eV, a typical value for In$^{3+}$ compounds. By increasing the zinc precursor concentration in the synthesis, a systematic shift of both the In 3d$_{5/2}$ (Figure 2a) and the Zn 2p$_{3/2}$ (Figure 2b) peaks to higher binding energies is observed. The In 3d$_{5/2}$ peak shifts up to 444.8±0.2 eV, for Zn/In=5, still consistent with a 3+ oxidation state. The Zn 2p$_{3/2}$ peak shifts from 1021.1±0.2 eV, for Zn/In=0.5, to 1021.4±0.2 eV, for Zn/In=5. Even though the Zn 2p$_{3/2}$ peak energies are close to those reported for Zn(II) phosphides, the observed trends (Figures 2c-d) are not consistent with the growth of a Zn-based phosphide shell as in that case the local In environment would not have changed and the In peaks would not have shifted. In line with previous work on alloyed QDs and in accordance with the XRD results, the fact that both In and Zn XPS peaks shift as the Zn/In ratio increases is interpreted as the modification of the chemical environment experienced by both In$^{3+}$ and Zn$^{2+}$ ions, as a consequence of the formation of an In$_x$Zn$_y$P alloy structure. Moreover, quantitative XPS analysis (shown as red squares in figure 1b) confirms the Zn/In values obtained by ICP-OES: as discussed in ref 42 and in ref 43 in the case of core/shell QDs, XPS would have been affected by the layered structure of the system. The agreement between XPS and ICP-OES results therefore strongly supports the formation of an In$_x$Zn$_y$P alloy structure.

A kinetic study of the synthesis was carried out in order to understand the formation mechanism of In$_x$Zn$_y$P alloy QDs. We monitored via ICP-OES the Zn/In ratio at different stages of the reaction (between 30s and 2h) for Zn/In=1.5 and Zn/In=4 feed ratios (Figure 3 a). Two possible pathways were considered: (i) after the nucleation and growth of InP QDs, In$^{3+}$ is replaced by Zn$^{2+}$ via a
cation exchange reaction;\textsuperscript{44,45} or (ii) In\textsuperscript{3+} and Zn\textsuperscript{2+} react simultaneously with P\textsuperscript{3−} directly forming alloyed In\textsubscript{x}Zn\textsubscript{y}P QDs. In scenario (i) we expect to see a significant increase in Zn\textsuperscript{2+} content at a certain stage during the reaction. The observed Zn/In ratio was roughly constant during the whole reaction, showing a slight variation from 1.45 to 1.80 in the case of Zn/In=1/5, and from 3.56 to 3.73 in the case of Zn/In=4. Absorption measurements (Figure 3 b, c and d) confirmed that the QDs were growing during the whole period shown in Figure 3 b. The results suggest that In\textsuperscript{3+} and Zn\textsuperscript{2+} react simultaneously with P\textsuperscript{3−} to form In\textsubscript{x}Zn\textsubscript{y}P, as the Zn/In ratio remains constant during the reaction, ruling out any post-nucleation cation exchange process. This further indicates that the formation of a InP/Zn\textsubscript{3}P core shell structure is unlikely.

The In\textsubscript{x}Zn\textsubscript{y}P alloy bulk structure has not been reported to date, and the pure materials (x=0 and y=0, i.e. InP, Zn\textsubscript{3}P\textsubscript{2} or Zn\textsubscript{2}P) have different crystal structure (Figure 1d). However, our results demonstrate that a metastable cubic phase of In\textsubscript{x}Zn\textsubscript{y}P alloy can exist at the nanocrystal level. This is not completely surprising because zinc phosphide can crystallize in a cubic Zn\textsubscript{3}P\textsubscript{2} phase in which the anion framework is almost identical to that of InP.\textsuperscript{46–48} Both structures exhibit an almost identical FCC phosphorous sublattice (with a P-P bonds length of 4.02 Å for Zn\textsubscript{3}P\textsubscript{2}, and 4.15 Å for InP) where the cations occupy tetrahedral sites (see sketch in Figure 1c and S10). The isomorphism of these two structures suggests that an alloy can form.

An important aspect to consider is the charge of the In\textsubscript{x}Zn\textsubscript{y}P alloy QDs. As argued above, the alloyed structure is formed when In\textsuperscript{3+} is replaced with Zn\textsuperscript{2+} creating a charge imbalance. However, we estimated the net charge in our QDs using ζ-potential measurements (see SI for details), and the results (depicted in Figure S11) indicate that for all samples the charge is zero within the experimental error, suggesting that a net balancing of the charges occurred during the formation of such alloys. We can envisage four charge compensating scenarios: (i) p-doping
could occur to compensate for the net negative charge. However, this would most likely lead to efficient Auger quenching and an absorption bleach,\(^{49}\) of which we found no indications in the UV-VIS absorption and emission measurements (see Figure 4a below). \((ii)\) \(\text{Zn}^{2+}\) could occupy both interstitial and substitutional positions in the NC: in this case, every three \(\text{Zn}^{2+}\) incorporated in the NCs only two \(\text{In}^{3+}\) sites would be occupied, preserving neutrality. A comparison between experimental and simulated XRD patterns presented above suggests that this scenario is improbable. \((iii)\) negatively charged \(x\)-type palmitate ligands could desorb from the surface to preserve the charge.\(^{38,39}\) At present we have no evidence in favour or against this scenario. \((iv)\) Phosphorus vacancies could form to balance the charge (one for every three \(\text{In}^{3+}\) replaced by three \(\text{Zn}^{2+}\)). This hypothesis has already been taken into consideration in the DFT calculations described above and therefore it appears likely.

To decide if scenario \(iv\) applies to our QDs we carried out TEM-EDX analysis to determine the \(\text{In}/\text{Zn}/\text{P}\) ratios (See SI for details and table S1). Three different \(\text{In}_x\text{Zn}_y\text{P}\) samples with \(\text{Zn}/\text{In}\) ratios of 0, 0.3 and 1.3 were analysed. As more zinc is added to the QDs, the amount of phosphorous decreases from 27% (pure \(\text{InP}\)) to 19% (\(\text{Zn}/\text{In}=1.3\)), in line with the formation of phosphorous vacancies. However, the decrease in phosphorous does not keep up with the amount of zinc added. A tentative explanation for this observation is that a fraction of the zinc atoms (roughly 1/3 based on the charge balance with phosphorous) is included in the crystal lattice, while the remaining fraction is localized at the surface of the QDs.

The inclusion of zinc inside the \(\text{InP}\) lattice does not only influence the structure of the resulting QDs, but also their optical properties. Figure 4a shows the absorption (solid line) and the PL emission (dashed line) of \(\text{In}_x\text{Zn}_y\text{P}\) QDs with different \(\text{Zn}/\text{In}\) ratios. The variation of the exciton absorption peak maximum \((\lambda_{\text{Abs,max}}, \text{black dots})\) and the PL maximum \((\lambda_{\text{PL,max}}, \text{red dots})\) versus
the Zn/In ratio measured with ICP-OES are shown in Figure 4b. By increasing the concentration of zinc up to 1.5, a systematic blue-shift of both $\lambda_{\text{Abs,max}}$ and $\lambda_{\text{PL,max}}$ was observed, while after further incorporation of Zn$^{2+}$ (i.e. for Zn/In > 1.5), the trend reversed and a red-shift of the optical features was observed. A possible explanation for the blue shift could be that the presence of Zn-carboxylates in the reaction mixture influences the kinetics of the reaction, leading to smaller particles. However, TEM measurements indicated that In$_x$Zn$_y$P QDs having different Zn concentrations have comparable sizes (see SI, figure S1). An alternative explanation is that the alloyed In$_x$Zn$_y$P material has a different (bulk) bandgap than pure InP. Indeed, it is well known that in many bulk semiconductor alloys there is a direct correlation between the alloy composition and its band gap. In addition, the degree of quantum confinement could also be different, if the effective masses of electrons and holes change in the alloy. These combined effects could result in the strongly non-linear trends observed in Figure 4b.

As previously reported, the addition of zinc precursor has a clear influence on the removal of trap states. While the PL emission spectrum of the pure InP QDs (Figure 4a black curve) is characterized by a broad secondary peak at lower energies, usually assigned to defect emission, this peak was suppressed upon the introduction of zinc, as has been previously observed by Thuy et al. At the same time, the PL QY of the alloyed QDs increased from about 0-1% in pure InP up to 20% for Zn/In = 1.5 (figure 4c) and the PL decay became longer (see figure S12 and table S2), suggesting that the Zn$^{2+}$ ions, in addition to being incorporated in the QD lattice, could passivate the surface of the QDs.

The possibility of tuning both optical properties and lattice parameters of the In$_x$Zn$_y$P QDs by varying only one synthetic parameter, i.e. the amount of Zn precursor, is promising for achieving high PL QY QDs upon the epitaxial growth of a lattice-matching shell material. Depending on
the amount of zinc incorporated, the lattice constants of the QDs, which were calculated from the corresponding XRD patterns using a Nelson-Riley plot,\textsuperscript{33,34} can be tuned linearly from 5.93 Å, in the case of pure InP, to 5.39 Å for In\textsubscript{x}Zn\textsubscript{y}P with Zn/In = 4.4 (Figure 5a). This range spans the lattice constants of most commonly used shell materials, like ZnSe \((a=5.66 \text{ Å})\),\textsuperscript{29} GaP \((a=5.45 \text{ Å})\)\textsuperscript{28} and ZnS \((a=5.42 \text{ Å})\),\textsuperscript{29} which all have the same zinc blende crystal structure and have suitable type-I band offsets. Our approach therefore offers a simple way to overcome the problem of the lattice mismatch in core/shell structures.

As a proof of concept, we synthesised five different In\textsubscript{x}Zn\textsubscript{y}P cores by varying the Zn/In ratio, in order to obtain QDs with different lattice constants: Zn/In = 2.0 \((a=5.61 \text{ Å})\), Zn/In = 2.4 \((a=5.52 \text{ Å})\), Zn/In = 2.8 \((a=5.49 \text{ Å})\), Zn/In = 3.7 \((a=5.45 \text{ Å})\) and Zn/In = 3.6 \((a=5.44 \text{ Å})\). For each core we grew a ZnSe\textsubscript{z}S\textsubscript{1-z} shell varying the shell composition from ZnSe \((z=1)\) to ZnS \((z=0)\) (see Experimental section and SI for details) and, thus, the corresponding lattice parameters. ZnSe\textsubscript{z}S\textsubscript{1-z} is a well-known alloy whose lattice parameters are reported in literature and can be finely tuned from 5.67 Å for \(z=1\) to 5.41 Å for \(z=0\) (see figure S13a) varying the material’s composition.\textsuperscript{29} A calibration curve of the shell lattice constant as a function of \(z\) is constructed from literature data and shown in Figure S13 of the SI. The Se and S fractions in the core/shell samples were determined by ICP (OES) and the results are given in Table S3. From these results the value of \(z\) is extracted and used to calculate the lattice constants of the ZnSe\textsubscript{z}S\textsubscript{1-z} shells, using the calibration curve (figure S13b). Absorption and emission spectra of the In\textsubscript{x}Zn\textsubscript{y}P/ ZnSe\textsubscript{z}S\textsubscript{1-z} core/shell are reported in figure S14 in the SI.

Figure 5b shows a 2D plot of the PL QY (color scale) vs. the lattice constant of the core \(a_1\) (x-axis) and the lattice constant of the shell \(a_2\) (y-axis). The dashed line indicates lattice matching between core and shell. (See also figure S13 b). For each different In\textsubscript{x}Zn\textsubscript{y}P core the highest PL
QY value (up to 60%) was recorded when the lattice mismatch was minimum. These results demonstrate that interfacial lattice mismatch is the dominant cause of a low PL QY in these core-shell QDs and that it can be reduced significantly by designing the core crystal structure with specific lattice spacing. The overall PL QY is highest for \(\text{In}_x\text{Zn}_y\text{P}\) cores with a Zn/In ratio of 2.8 and a matching \(\text{ZnSe}_z\text{S}_{1-z}\) shell with \(a=5.49\) Å. However, not for every starting core the PL reaches the same maximum, which suggests that in addition to core/shell lattice matching, other parameters also play a role. Still, it is clear that for any core composition the QY of the resulting core/shell QDs can only be high for fully matched core and shell lattices.

**CONCLUSIONS**

In summary, we have presented an original way to overcome the problem of the lattice mismatch in InP based core/shell structures. We developed a method to design the core crystal structure with specific lattice spacing such that it matches the lattice of different shell materials. This is achieved by alloying InP with Zn\(^{2+}\) ions, leading to luminescent \(\text{In}_x\text{Zn}_y\text{P}\) QDs whose lattice constant can be finely tuned by varying the concentration of Zn, and the composition of the \(\text{In}_x\text{Zn}_y\text{P}\) alloy nanocrystals could be tuned up to a Zn/In ratios as high as 20. A combination of XRD, ICP-OES and XPS results, combined with DFT modelling, showed that Zn\(^{2+}\) is included as a substitutional dopant on In\(^{3+}\) sites producing a systematic contraction of the crystal lattice. The possibility of tuning the lattice constant of the In based QDs expands the range of shell materials compatible with InP. Additionally, we demonstrated that the PL QY is highest when the lattices parameters of core and shell are matched, such that a maximum PL QY of 60% could be achieved in the core/shell nanocrystals. Our method represents a simple and effective
way to alleviate lattice mismatch in core/shell QDs, paving the way for the fabrication of defect free QD heterostructures.

Figure 1- (a) TEM image of InP QDs (b) Plot of the Zn/In ratio measured in In$_x$Zn$_y$P QDs versus the corresponding precursors feed ratio. The plot follows a linear trend (green line) up to Zn/In=5 after, after which the Zn/In ratio reaches saturation (red dashed line). The relative amounts of In and Zn were measured via ICP-OES elemental analysis (black empty dots) and confirmed by XPS (red solid squares). (c) Atomic scheme representing a (111) lattice facet of InP (upper panel) and Zn$_3$P$_2$ (lower panel) cubic phase. This shows that the P sublattice in Zn$_3$P$_2$ is the same as for InP. (d) XRD patterns obtained from drop-cast solutions of In$_x$Zn$_y$P QDs, with different Zn/In ratios. The corresponding bulk reflections of zinc blende InP (black, ICSD code 24517), tetragonal Zn$_2$P (dark green, ICSD code 24487) and monoclinic Zn$_3$P (light green, ICSD code 60011), tetragonal Zn$_3$P$_2$ (light blue, ICSD code 250159) and cubic Zn$_3$P$_2$ (dark blue, ICSD code 24487) are reported in the lower and upper panels, respectively. (e) DFT-calculated XRD
patterns of In$_x$Zn$_y$P (1.5 nm) QDs considering Zn$^{2+}$ as substitutional (upper panel), substitutional + interstitial (middle panel) or interstitial (lower panel) dopant in the zinc blend InP crystal structure.

**Figure 2** (a-b) In 3d$_{5/2}$ and the Zn 2p$_{3/2}$ XPS spectra for several In$_x$Zn$_y$P samples. Each spectrum is labelled with the Zn/In feed ratio. (c-d) The position of In and Zn peaks shifts to higher binding energy values when increasing the Zn/In feed ratio, as summarized in panels c and d.
Figure 3- (a) Plot of the Zn/In ratios measured with ICP- OES at different stages of the reaction for In$_x$Zn$_y$P for Zn/In feed ratios of 1.5 and 4. (b) Plot of the peak absorption wavelength vs. time for a In$_x$Zn$_y$P QD synthesis with Zn/In = 4 (black curve) and Zn/In = 1.5 (red curve). (b, c) Evolution of the absorption spectra over time during the reaction for In$_x$Zn$_y$P with (c) Zn/In = 4 and Zn/In = 1.5 (d).

Figure 4- (a) Normalized absorption and PL spectra of In$_x$Zn$_y$P QDs. Except for a variable Zn/In ratio, all other synthesis conditions were identical. (b) Plot of $\lambda_{\text{max}}$ (nm) for the absorption (black dots) and PL emission (red squares) wavelengths as a function of the Zn/In molar ratio obtained by ICP(OES) analysis. Dashed lines represent a guide to the eye (c) Plot of the PL QY (%) of In$_x$Zn$_y$P QDs as function of the Zn/In molar ratio obtained by ICP(OES) elemental analysis.
Figure 5 (a) Plot of the lattice constant of In$_x$Zn$_y$P QDs as a function of the Zn/In measured ratio. Dashed lines indicate the lattice constants of bulk InP (black, ICSD code 24517), ZnSe (green, ICSD code 77091), GaP (red, ICSD code 77087) and ZnS (blue, ICSD code 60378). (b) Color plot of the PL QY versus the lattice constant of the ZnSe$_x$S$_{1-x}$ shell $a_2$ and the lattice constant of the core $a_1$. The data points (black empty dots) were interpolated with a linear fit. The dashed line indicates lattice matching between core and shell ($a_1$=a$_2$).

ASSOCIATED CONTENT

Supporting Information. Experimental details and additional figures. This material is available free of charge via

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REFERENCES


(9) Yang, X.; Zhao, D.; Leck, K. S.; Tan, S. T.; Tang, Y. X.; Zhao, J.; Demir, H. V.; Sun, X. W. Full Visible Range Covering InP/ZnS Nanocrystals with High Photometric


